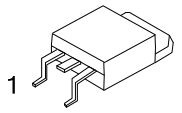
7NM65-FD2

Power MOSFET

7A, 650V N-CHANNEL SUPER-JUNCTION MOSFET



TO-252

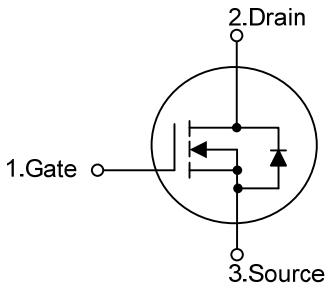
■ DESCRIPTION

The **UTC 7NM65-FD2** is a Super Junction MOSFET Structure and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and a high rugged avalanche characteristics. This power MOSFET is usually used at DC-DC, AC-DC converters for power applications.

■ FEATURES

* $R_{DS(ON)}$ < 1.0 Ω @ V_{GS}=10V, I_D=3.5A
* By using Super Junction Structure
* Fast Switching
* With 100% Avalanche Tested

■ SYMBOL



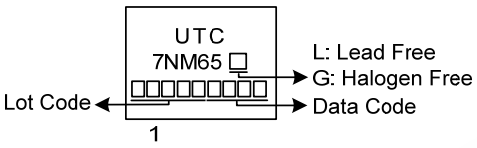
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
7NM65L-TN3-R	7NM65G-TN3-R	TO-252	G	D	S	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

7NM65G-TN3-R (1)Packing Type	(1) R: Tape Reel
(2)Package Type	(2) TN3: TO-252
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

■ MARKING



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■ ABSOLUTE MAXIMUM RATINGS (T_C = 25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain to Source Voltage		V_{DSS}	650	V
Gate to Source Voltage		V_{GSS}	±30	V
Continuous Drain Current	Continuous	I_D	7	A
Pulsed Drain Current	Pulsed (Note 2)	I_{DM}	21	A
Avalanche Energy	Single Pulsed (Note 3)	E_{AS}	162	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	8	V/ns
Power Dissipation		P_D	60	W
Junction Temperature		T_J	+150	°C
Storage Temperature		T_{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
2. Repetitive Rating : Pulse width limited by maximum junction temperature.
3. L=144mH, I_{AS}=1.5A, V_{DD}= 50V, R_G=25Ω, Starting T_J=25°C.
4. I_{SD} ≤10A, di/dt ≤200A/μs, V_{DD} ≤BV_{DSS}, Starting T_J=25°C.

■ THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	110	°C/W
Junction to Case	θ_{JC}	2.08	°C/W

■ ELECTRICAL CHARACTERISTICS (T_J =25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V, I_D=250μA	650			V
Drain-Source Leakage Current	I_{DSS}	V_{DS}=650V, V_{GS}=0V			10	μA
Gate-Source Leakage Current	I_{GSS}	V_{DS}=0V ,V_{GS}=±30V			±100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(TH)}$	V_{DS}= V_{GS}, I_D=250μA	2.5		4.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	V_{GS}=10V, I_D=3.5A			1.0	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	V_{DS}=25V,V_{GS}=0V, f=1.0MHz		350		pF
Output Capacitance	C_{OSS}			300		pF
Reverse Transfer Capacitance	C_{RSS}			30		pF
SWITCHING PARAMETERS						
Turn-ON Delay Time (Note 1)	$t_{D(ON)}$	V_{DD}=300V, V_{GS}=10V, I_D=7.0A, R_G=25Ω (Note 1, 2)		0.4		ns
Rise Time	t_R			10.2		ns
Turn-OFF Delay Time	$t_{D(OFF)}$			38		ns
Fall-Time	t_F			20.2		ns
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Maximum Body-Diode Continuous Current	I_S				7	A
Maximum Body-Diode Pulsed Current	I_{SM}				21	A
Drain-Source Diode Forward Voltage (Note 1)	V_{SD}	I_S =7.0A, V_{GS}=0V			1.4	V
Body Diode Reverse Recovery Time (Note 1)	t_{rr}	I_S =7.0A, V_{GS}=0V		166		ns
Body Diode Reverse Recovery Charge	Q_{rr}	dI_F/dt=100A/μs		1		μC

Notes: 1. Pulse Test : Pulse width ≤ 300μs, Duty cycle ≤ 2%
2. Essentially independent of operating temperature

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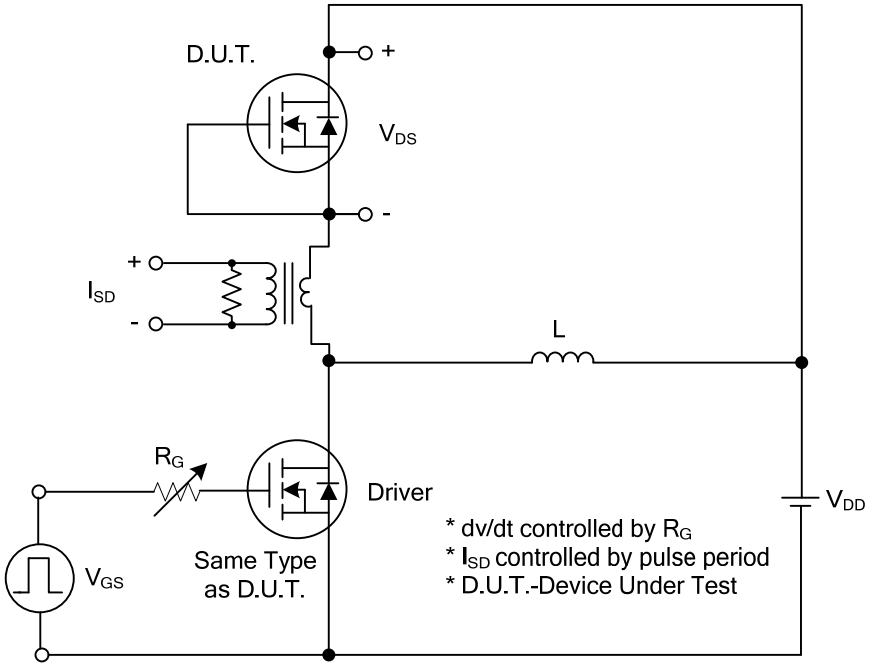
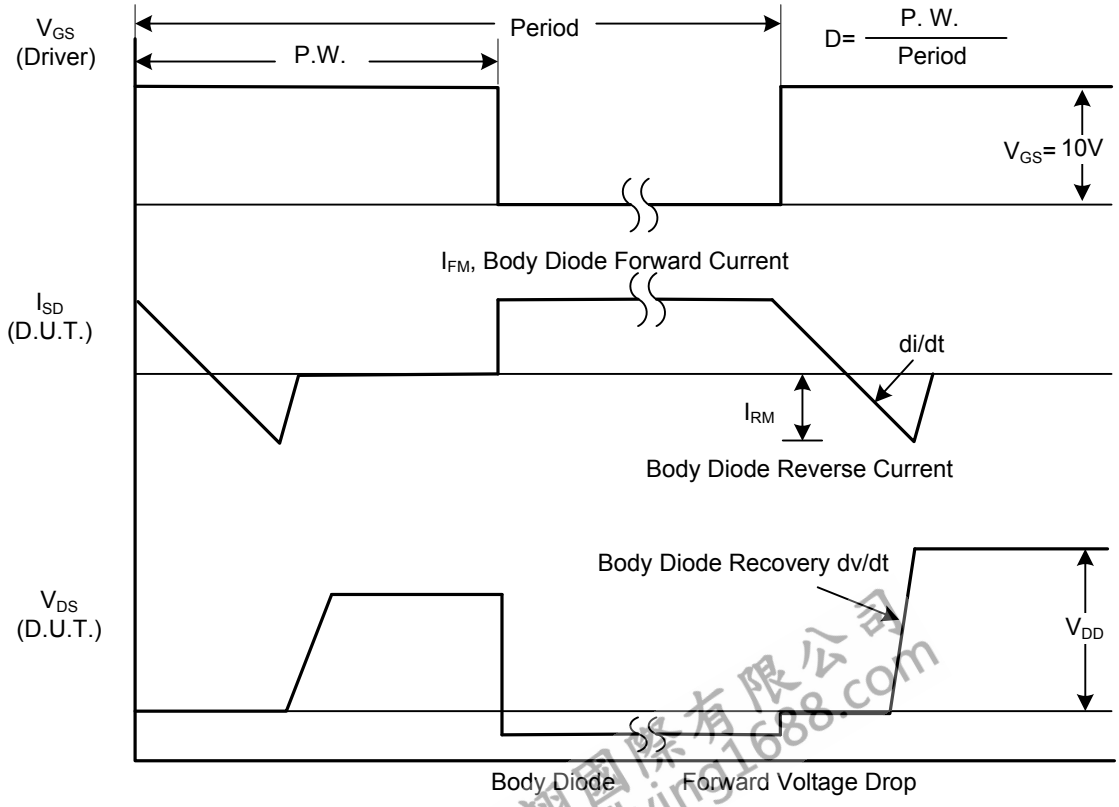
■ TEST CIRCUITS AND WAVEFORMS



Peak Diode Recovery dv/dt Test Circuit



Peak Diode Recovery dv/dt Waveforms

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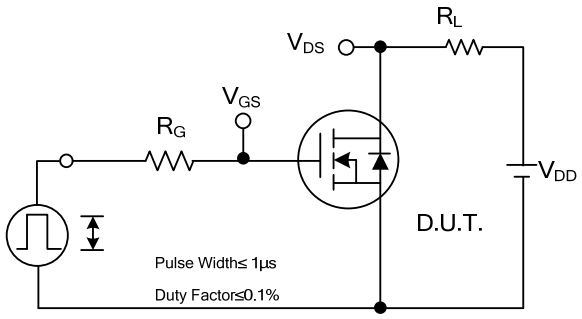
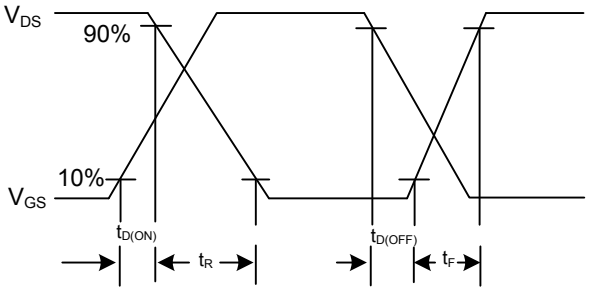
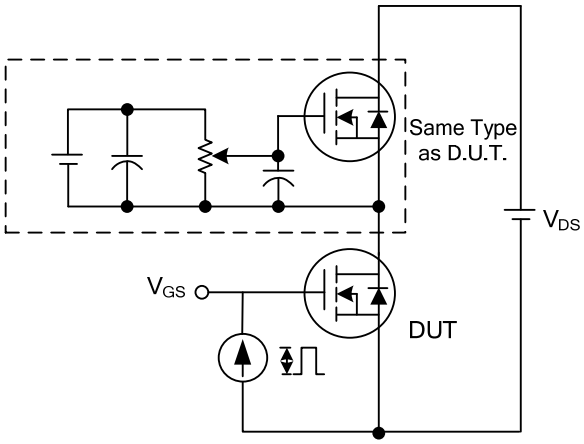
■ TEST CIRCUITS AND WAVEFORMS (Cont.)



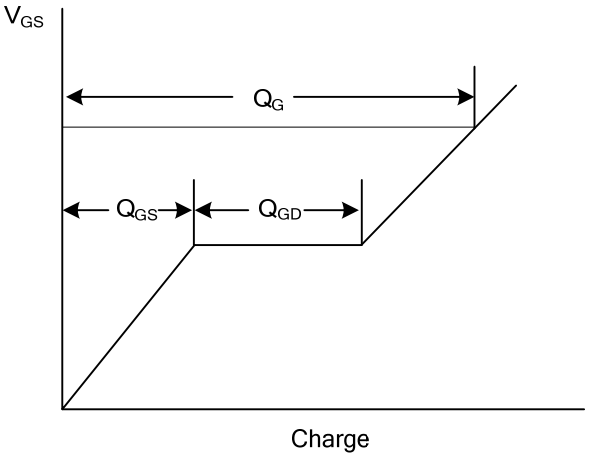
Switching Test Circuit



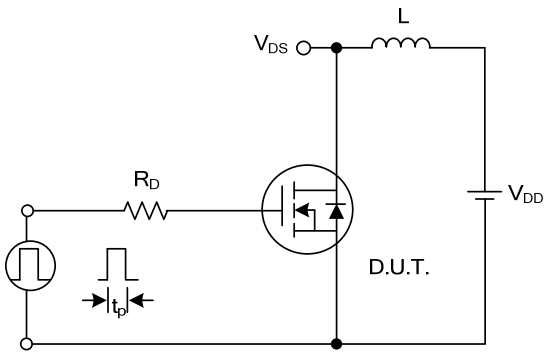
Switching Waveforms



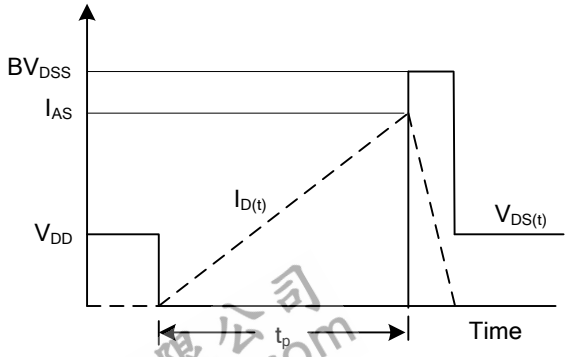
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

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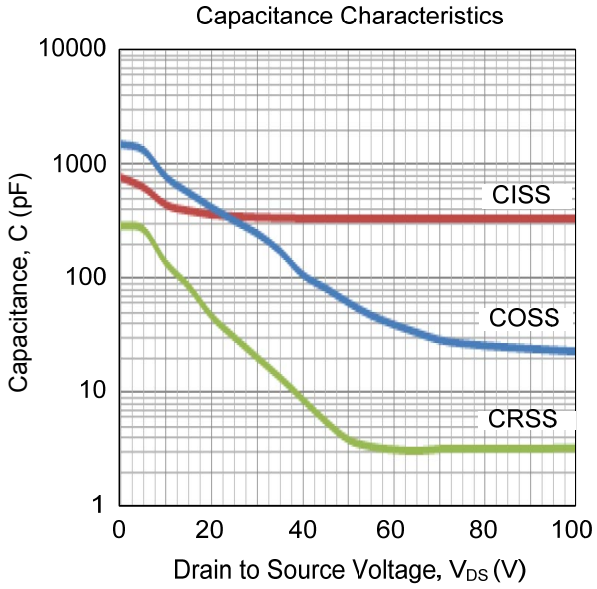
■ TYPICAL CHARACTERISTICS



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